

Product Summary

$V_{(BR)DSS}$	$R_{DS(on)TYP}$	I_D
60V	80mΩ@10V	4A
	90mΩ@4.5V	

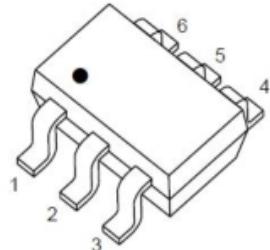
Feature

- High power and current handing capability
- Surface mount package

Applications

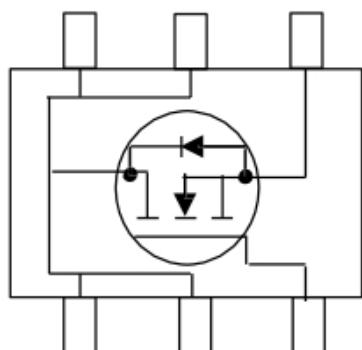
- Battery Switch
- DC/DC Converter

Package



SOT-23-6L

Circuit diagram



Marking



Absolute maximum ratings

($T_a=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	60	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current	I_D	4	A
Pulsed Drain Current ¹⁾	I_{DM}	16	A
Maximum Power Dissipation	P_D	1.5	W
Thermal Resistance from Junction to Ambient ²⁾	$R_{\theta JA}$	83.3	$^\circ\text{C}/\text{W}$
Junction Temperature	T_J	150	$^\circ\text{C}$
Storage Temperature	T_{STG} ,	-55 To 150	$^\circ\text{C}$

Electrical characteristics

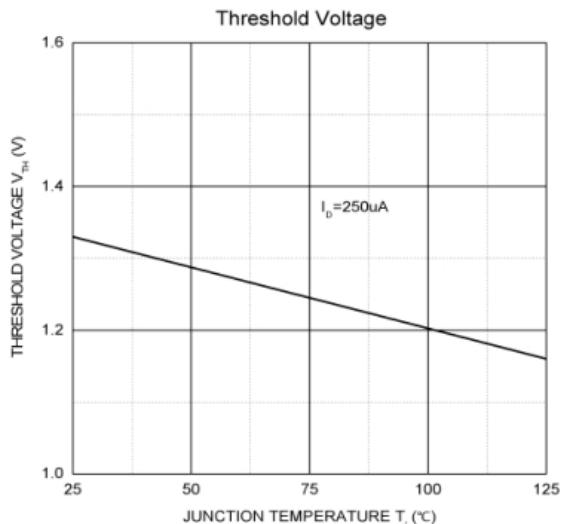
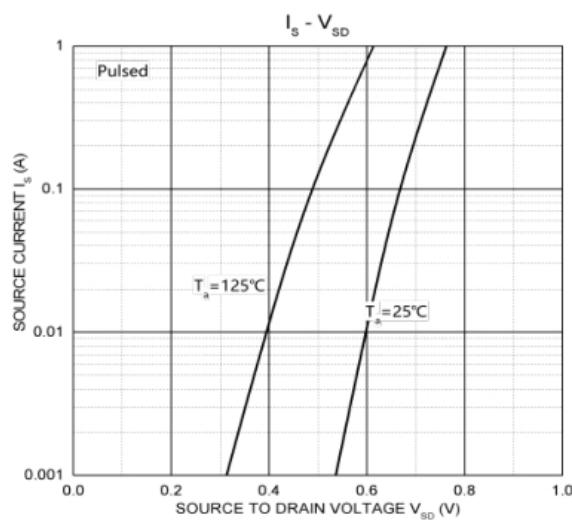
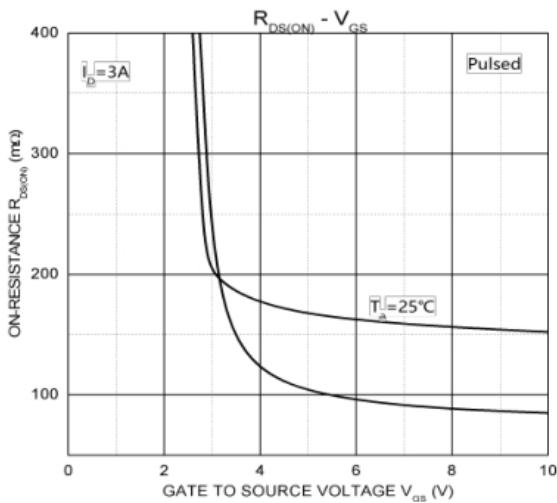
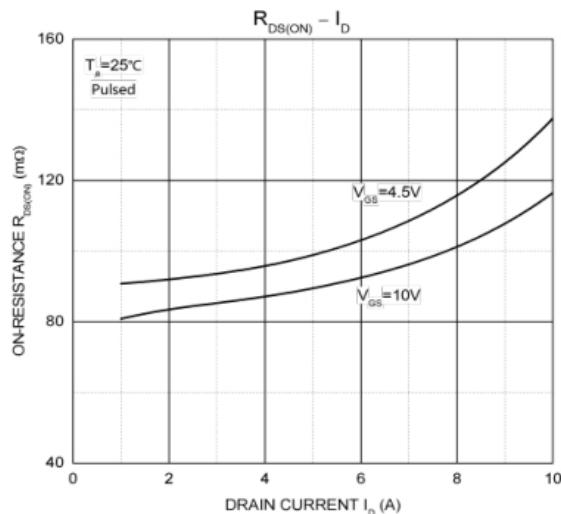
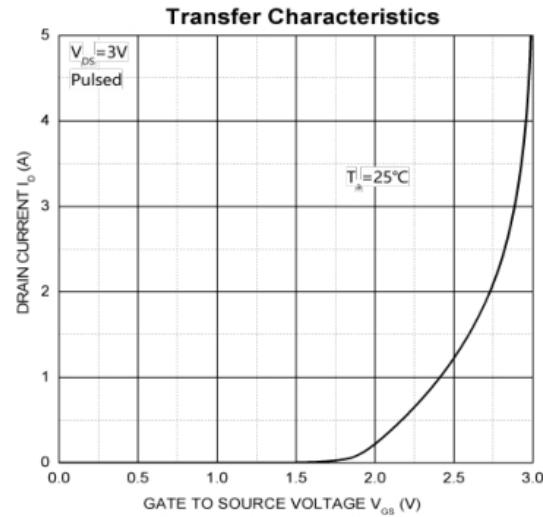
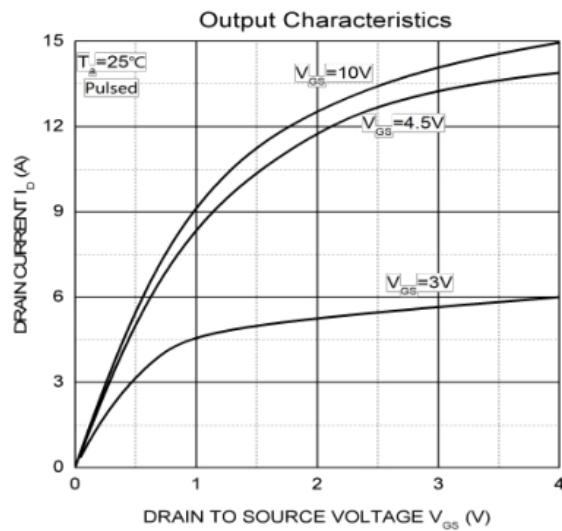
($T_A=25^\circ\text{C}$, unless otherwise noted)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	$\text{BV}_{(\text{BR})\text{DSS}}$	$V_{GS} = 0\text{V}, I_D = 250\mu\text{A}$	60			V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 60\text{V}, V_{GS} = 0\text{V}$			1	μA
Gate-Body Leakage Current	I_{GSS}	$V_{GS} = \pm 20\text{V}, V_{DS} = 0\text{V}$			± 100	μA
Gate Threshold Voltage ³⁾	$V_{GS(\text{th})}$	$V_{DS} = V_{GS}, I_D = 250\mu\text{A}$	0.8	1.2	2	V
Drain-Source On-State Resistance ³⁾	$R_{DS(\text{on})}$	$V_{GS} = 10\text{V}, I_D = 3\text{A}$		80	100	$\text{m}\Omega$
		$V_{GS} = 4.5\text{V}, I_D = 2\text{A}$		90	120	
Dynamic Characteristics⁽⁴⁾						
Input capacitance	C_{iss}	$V_{DS}=30\text{V}, V_{GS}=0\text{V}, f=1\text{MHz}$		330		pF
Output capacitance	C_{oss}			90		
Reverse transfer capacitance	C_{rss}			17		
Switching Characteristics⁽⁴⁾						
Total Gate Charge	Q_g	$V_{DS}=30\text{V}, V_{GS}=4.5\text{V}, I_D = 3\text{A}$		5.1		pF
Gate-Source Charge	Q_{gs}			1.3		
Gate-Drain Charge	Q_{gd}			1.7		
Turn-on Delay Time	$T_{d(\text{on})}$	$V_{GS}=10\text{V}, V_{DD}=30\text{V}, I_D = 1.5\text{A}, R_G = 1\Omega, R_{Gen} = 3\Omega$		13		nS
Turn-on Rise Time	T_r			51		
Turn-Off Delay Time	$T_{d(\text{off})}$			19		
Turn-Off Fall Time	t_f			12		
Drain-Source Diode Characteristics⁽⁴⁾						
Body Diode Voltage	V_{SD}	$V_{GS}=0\text{V}, I_S=3\text{A}$			1.2	V

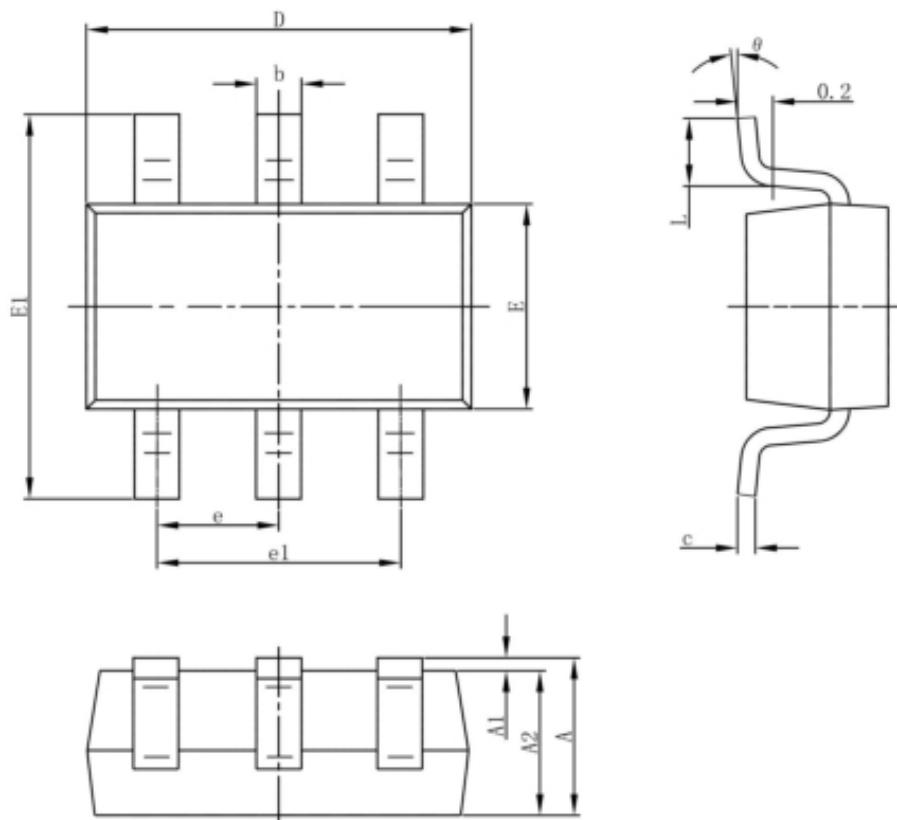
Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.
2. Surface Mounted on FR4 Board, $t \leq 10$ sec.
3. Pulse Test: Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$.
4. Guaranteed by design, not subject to production

Typical Characteristics



SOT-23-6L Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°